SUP70060E

Vishay Siliconix

www.vishay.com

N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω) MAX.	I _D (A)	Q _g (TYP.)	
100	0.0058 at V_{GS} = 10 V	131	53.5 nC	
100	0.0064 at V_{GS} = 7.5 V	129		

TO-220AB

Ordering Information:

SUP70060E-GE3 (lead (Pb)-free and halogen-free)

FEATURES

- ThunderFET[®] power MOSFET
- Maximum 175 °C junction temperature
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless other	wise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	100	N/	
Gate-Source Voltage		V _{GS}	± 20	V	
	T _C = 25 °C		131	^	
Continuous Drain Current (T _J = 150 °C)	T _C = 125 °C	I _D	75		
Pulsed Drain Current (t = 100 μs)		I _{DM}	240	A	
Avalanche Current	L = 0.1 mH		50		
Single Avalanche Energy ^a		E _{AS}	125	mJ	
Maximum Power Dissipation ^a	T _C = 25 °C	P _D	200 ^b	w	
	T _C = 125 °C	۳D	66.6 ^b	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)	R _{thJC}	0.75	0/10	

Notes

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a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR4 material).

HALOGEN

FREE

D

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS}=0~V,~I_D=250~\mu A$	100	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},\ I_D=250\ \mu A$	2	-	4	v
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
		$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	1	μA
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 100 V, V_{GS} = 0 V, T_J = 125 $^\circ C$	-	-	100	
		V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 175 °C	-	-	2	mA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \! \geq \! 10 \text{ V}, V_{GS} \! = \! 10 \text{ V}$	90	-	-	А
Drain-Source On-State Resistance a		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	0.0048	0.0058	Ω
Drain-Source On-State Resistance a	R _{DS(on)}	$V_{GS} = 7.5 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	0.0050	0.0064	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	85	-	S
Dynamic ^b						
Input Capacitance	C _{iss}		-	3330	-	pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 50 V, f = 1 MHz	-	1395	-	
Reverse Transfer Capacitance	C _{rss}		-	95	-	
Total Gate Charge ^c	Qg		-	53.5	81	
Gate-Source Charge ^c	Q _{gs}	$V_{DS}=50$ V, $V_{GS}=10$ V, $I_{D}=30$ A	-	14.5	-	nC
Gate-Drain Charge ^c	Q _{gd}		-	13.2	-	
Gate Resistance	R _g	f = 1 MHz	0.9	1.9	3.8	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	13	26	
Rise Time ^c	tr	$V_{DD} = 50 \text{ V}, \text{ R}_{L} = 1.67 \Omega$	-	22	44	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 30$ Å, $V_{GEN} = 10$ V, $R_g = 1 \Omega$	-	27	54	ns
Fall Time ^c	t _f		-	9	18	1
Drain-Source Body Diode Ratings an	nd Characteria	stics ^b (T _C = 25 °C)	-			
Pulsed Current (t = 100 µs)	I _{SM}		-	-	240	А
Forward Voltage ^a	V _{SD}	$I_F = 30 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.86	1.4	V
Reverse Recovery Time	t _{rr}		-	88	176	ns
Peak Reverse Recovery Charge	I _{RM(REC)}	I _F = 30 A, di/dt = 100 A/μs	-	5	10	А
Reverse Recovery Charge	Q _{rr}		-	0.22	0.44	μC

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

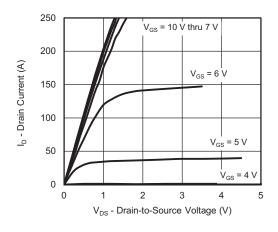
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

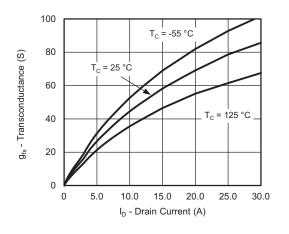
2



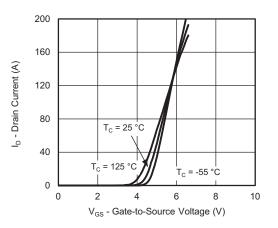
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



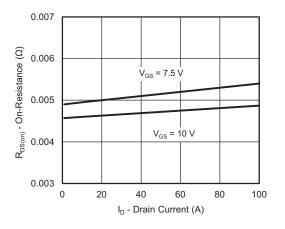
Output Characteristics



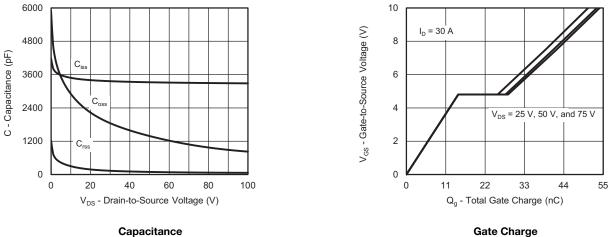
Transconductance



Transfer Characteristics



On-Resistance vs. Drain Current



Capacitance

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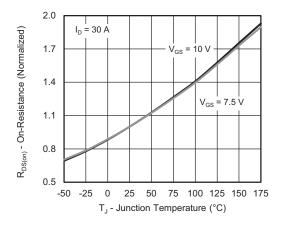
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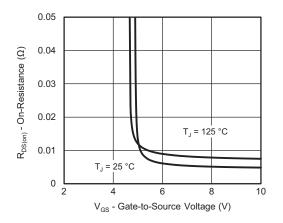
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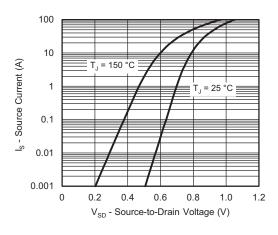
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



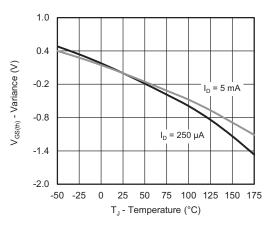
On-Resistance vs. Junction Temperature



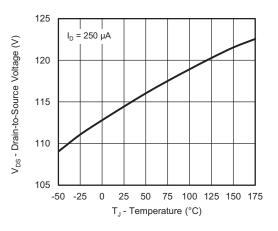
On-Resistance vs. Gate-to-Source Voltage



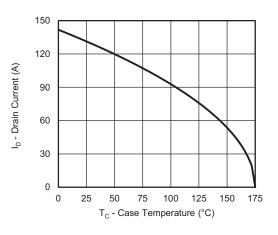
Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



Current De-Rating

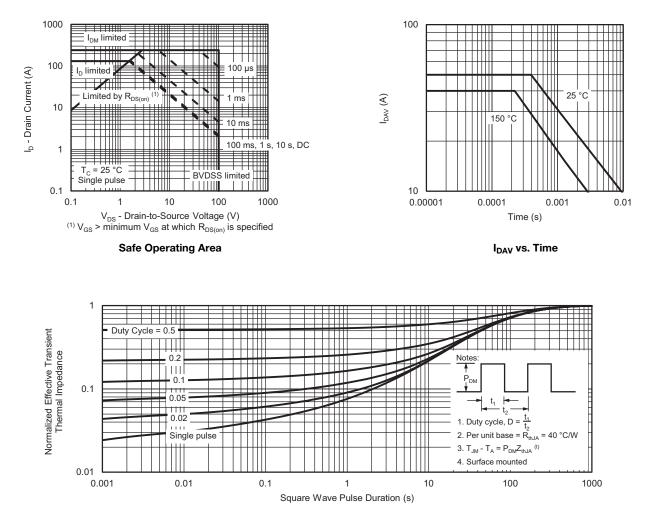
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

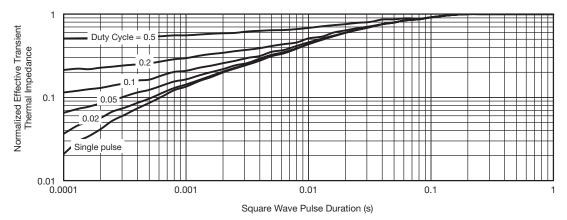


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

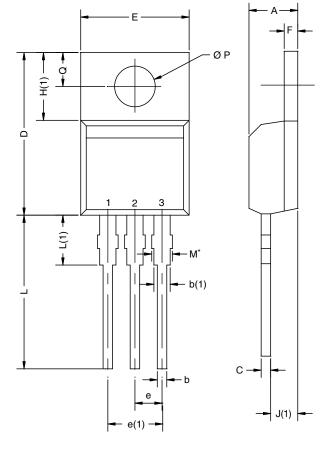
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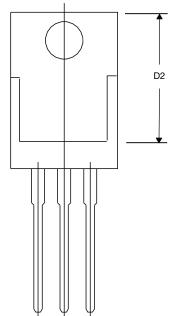
TO-220AB



	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØР	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: T14-0 DWG: 5471	0413-Rev. P, 1	16-Jun-14	•	•

Note

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



Revison: 16-Jun-14



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